## **Electronic supplementary information**

# 2 Interface Nanostructured Array Guided High Performance

### **3 Electrochemical Actuator**

4 G. Wu, G. H. Li, T. Lan, Y. Hu, Q. W. Li, T. Zhang and W. Chen\*

5 i-Lab, Suzhou Institute of Nano-tech and Nano-bionics, Chinese Academy of Sciences,

- 6 Suzhou 215123, P. R. China.
- 7 Corresponding author: wchen2006@sinano.ac.cn

### 2 **Experimental**

Materials. Natural graphite flake (325 meshes, 99.8%) was obtained from Sigma
Aldrich. Potassium peroxydisulfate (97%) and Phosphorous oxide (98%) were
obtained from Alfa-Aesa. EMIBF<sub>4</sub> (99%) obtained from Shanghai Cheng Jie
Chemical Co. Thermoplastic polyurethane (TPU) was obtained from DuPont<sup>TM</sup>. All
other chemicals were obtained from Sinopharm Chemical Reagent Co., Ltd and
deionized water was purified through Ultrapure Milli-Q system.

9 Preparation of actuators. GO was prepared by a modified Hummers method which has been described in our recent work.<sup>1,2</sup> The hybrid GO-MWCNTs was 10 synthesized by dispersing MWCNTs in GO solution in ice water bath under 200 W 20 11 kHz horn sonication treatment in a program of 2 s on and 5 s off for 30 minutes. Then 12 the GO-MWCNTs dispersion was reduced with N<sub>2</sub>H<sub>4</sub> in a 90 °C oil bath overnight to 13 form RGO-MWCNTs suspension. The obtained RGO-MWCNTs suspension was 14 filtrated with deionized water and re-dispersed in the same sonication program in N-15 Methyl pyrrolidone forming gel-like suspension of 1 mg/mL RGO-MWCNTs. The as 16 prepared 3 ml suspension was casted on glass substrate  $(2.5 \times 7.5 \text{ cm}^2 \text{ size})$  and heated 17 at 80 °C, obtaining dried RGO-MWCNTs film. Then we used tape to seal the edges of 18 the as-prepared film and placed the film into inorganic salt solution (the molar rate of 19 20 NiCl<sub>2</sub>:NH<sub>4</sub>Cl:NaOH is 1.15:6:2) and kept in an sealed container at 55  $^{\circ}$ C for 10 h, making Ni(OH)<sub>2</sub> vertically grew on the RGO-MWCNTs film. Further put the film 21 22 into the tube furnace, annealing at 400 °C for 2hour with Argon protection and

obtained the hierarchically nanocomposite VA-NiONWs@RGO-MWCNTs films. 1 The disordered NiO was synthesized by electrochemical method, which was 2 conducted under potentiostatic control (5 V) for 90 min in inorganic salt solution (the 3 molar rate of NaCl:NH<sub>4</sub>Cl:NaOH is 10:1:1.25) and calcined at 400 °C for 2 h in air, 4 forming disorder NiO. Then the NiO solution was casted on the on the half-dried 5 RGO-MWCNTs film and heated at 80 °C for 4 h, obtaining disorder NiO@RGO-6 MWCNTs film. In addition, 1 g TPU and 2 g EMIBF<sub>4</sub> was dissolved in 30 mL DMF 7 in 80 °C overnight to obtain uniform solution. 2 mL EMIBF<sub>4</sub>/TPU solution was casted 8 on a glass substrate (2.5×7.5 cm<sup>2</sup> size) and dried at 80°C for 3 days. Two piece of 9 electrode films were laminated on TPU/EMIBF4 film and heat pressed at 150°C for 3 10 hours and then 170°C overnight, obtaining a bimorph membrane of about 60 µm 11 thick, 5 mm width and 25 mm long actuator strip. 12

13 Actuator performance tests. The 25 x 5 mm sized actuator strips were all performed 14 in a two-electrode configuration with 22 mm free length from electrode contacts. 15 Actuation performance was tested by Multi-point step to the actuator strips using 16 CHI760D electrochemical work station. The displacement ( $\delta$ ) of the actuator was 17 measured by Keyence LK-G800 laser positioning system, where strain ( $\epsilon$ ), strain rate 18 ( $\epsilon_r$ ) and stress rate ( $\sigma_r$ ) generated in the electrode layers was estimated by the 19 following equations:<sup>3,4</sup>

20 
$$\varepsilon = \delta^* d/(\delta^2 + L^2), \varepsilon_r = 4^* \varepsilon^* f, \sigma_r = \sigma^* \varepsilon_r$$

Where d, δ, f, L are the thickness, displacement, frequency, free length of the actuator.
 For testing limited by Keyence LK-G800 laser positioning system, the large
 displacement can be accurate below 10 mm. So in this study, the displacements above
 10 mm were recorded from photography by camera.

Other measurements. Sonication was achieved by using a Fisher Scientific model 5 500 digital sonic dismembrator equipped with a 12.5 mm diameter disruptor horn. 6 Annealing treatment was processed using OTF-1200 tube furnace. FESEM was 7 recorded by Hitach S-4800. Mechanical tests were performed using an Instron 3365 8 universal testing machine. All electrochemical characterizations were recorded by 9 10 CHI760D electrochemical work station. Equivalent circuit analysis of impedance 11 spectra data was carried out using electrochemical impedance software (Scribner 12 Associates, Inc.) and the Chi-squared below 10-3. The actuation process and electrochemical characterization were all performed in a two-electrode configuration. 13 N2 adsorption/desorption analyses were carried out at 77 K using Micromeritics 14 15 ASAP 2050.

16

17

18

19



3 Scheme S1. The relative parameters of a bending graphene strip for curvature calculation.
4 Curvature=1/R.



Fig. S1 (a) The uptake capability of ILs in PVdF-HFP and TPU film and the mass ratio of ILs and TPU
(PVdF-HFP) is 2:1. (b) The strain-stress curve of PVdF-HFP and TPU supported ILs electrolyte layers.



- 2 Fig. S2 XRD patters for RGO-MWCNTs and VA-NiONWs@RGO-MWCNTs films, respectively.





7 Fig. S3 Surface morphology of electrode. SEM image of disordered NiO@RGO-MWCNTs electrode.



**Fig. S4.** The specific surface areas of different growth time based VA-NiONWs@RGO-MWCNTs

3 electrode films.

![](_page_6_Figure_4.jpeg)

6 Fig. S5 Illustration for impedance characterization. Illustration for impedance measurement7 characterization of three kinds of electrodes based actuators.

![](_page_7_Figure_0.jpeg)

![](_page_7_Figure_1.jpeg)

Fig. S6. Bode plots of RGO-MWCNTs, Disordered NiO@RGO-MWCNTs and VANiONWs@RGO-MWCNTs based actuators, respectively. Symbols denote experimental data,
while the continuous lines represent the fitted data.

![](_page_7_Figure_3.jpeg)

6 Table S1 EIS molding data. Parameter values from curve-fitting of the impedance results shown
7 in Fig.5a by using the equivalent circuit described in inset of Fig. 5a.

				0			
	$R_0/\Omega$	$R_{\rm l}/\Omega$	$Q_l/\mu F \ s^{n\text{-}1}$	n	$R_2/\Omega$	Q <sub>2</sub> /mF	$Z_{\rm w}$
RGO-MWCNTs	207.4	343.5	3.07x10 <sup>-2</sup>	0.602	/	/	/
Disordered NiO@RGO- MWCNTs	202.3	545.9	0.66x10 <sup>-2</sup>	0.523	3526	6.04	4750
VA-NiONWs@RGO-MWCNTs	287	228.3	3.35x10 <sup>-2</sup>	0.59	1320	13.3	2305

8

#### 9 References

10 1 D. Li, M. B. Muller, S. Gilje, R. B. Kaner and G. G. Wallace, Nat Nanotechnol, 2008, 3, 101-105.

11 2 J. H. Liu, Z. C. Wang, L. W. Liu and W. Chen, Phys Chem Chem Phys, 2011, 13, 13216-13221.

- 12 3 J. Li, W. Ma, L. Song, Z. Niu, L. Cai, Q. Zeng, X. Zhang, H. Dong, D. Zhao, W. Zhou and S. Xie,
   13 *Nano letters*, 2011, 11, 4636-4641.
- 14 4 R. Temmer, A. Maziz, C. Plesse, A. Aabloo, F. Vidal and T. Tamm, Smart Mater Struct, 2013, 22.